SLOS447G-SEPTEMBER 2004-REVISED FEBRUARY 2006

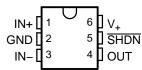
FEATURES

- 2.7-V and 5-V Performance
- Rail-to-Rail Output Swing
- Input Bias Current...1 pA Typ
- Input Offset Voltage...0.25 mV Typ
- Low Supply Current...100 μA Typ
- Low Shutdown Current...45 pA Typ
- Gain Bandwidth of 1 MHz Typ
- Slew Rate...1 V/μs Typ
- Turn-On Time From Shutdown...5 μs Typ
- Input Referred Voltage Noise (at 10 kHz)...
 20 nV/√Hz
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

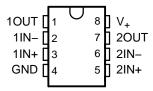
APPLICATIONS

- Cordless/Cellular Phones
- Consumer Electronics (Laptops, PDAs)
- Audio Pre-Amps for Voice
- Portable/Battery-Powered Electronic Equipment
- Supply-Current Monitoring
- Battery Monitoring
- Buffers
- Filters
- Drivers

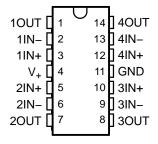
LMV341...DBV (SOT-23) OR DCK (SC-70) PACKAGE (TOP VIEW)



LMV342...D (SOIC) OR DGK (MSOP) PACKAGE (TOP VIEW)



LMV344...D (SOIC) OR PW (TSSOP) PACKAGE (TOP VIEW)



DESCRIPTION/ORDERING INFORMATION

The LMV341, LMV342, LMV344 devices are single, dual, and quad CMOS operational amplifiers, respectively, with low voltage, low power, and rail-to-rail output swing capabilities. The PMOS input stage offers an ultra-low input bias current of 1 pA (typ) and an offset voltage of 0.25 mV (typ). The single supply amplifier is designed specifically for low-voltage (2.7 V to 5 V) operation, with a wide common-mode input voltage range that typically extends from -0.2 V to 0.8 V from the positive supply rail. The LMV341 (single) also offers a shutdown (SHDN) pin that can be used to disable the device. In shutdown mode, the supply current is reduced to 33 nA (typ). Additional features of the family are a 20-nV/ $\sqrt{\text{Hz}}$ voltage noise at 10 kHz, 1-MHz unity-gain bandwidth, 1-V/ μ s slew rate, and 100- μ A current consumption per channel.

Offered in both the SOT-23 and smaller SC-70 packages, the LMV341 is suitable for the most space-constraint applications. The LMV342 dual device is offered in the standard SOIC and MSOP packages. An extended industrial temperature range from -40°C to 125°C makes these devices suitable in a wide variety of commercial and industrial environments.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SLOS447G-SEPTEMBER 2004-REVISED FEBRUARY 2006

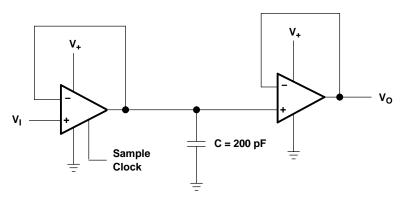


ORDERING INFORMATION

T _A		PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING (2)
		SOT-23 – DBV	Reel of 3000	LMV341IDBVR	RC9_
	Single	301-23 - DBV	Reel of 250	LMV341IDBVT	PREVIEW
	Sirigle	SC-70 – DCK	Reel of 3000	LMV341IDCKR	R4_
			Reel of 250	LMV341ICKVT	PREVIEW
	Dual	SOIC – D MSOP/VSSOP – DGK	Tube of 75	LMV342ID	MV342I
–40°C to 125°C			Reel of 2500	LMV342IDR	1010 3421
-40 C to 125 C			Reel of 250	LMV342IDGK	RP_
		WSOP/VSSOP - DGK	Reel of 2500	LMV342IDGKR	KF_
		SOIC - D	Tube of 50	LMV344ID	LMV344I
	Quad	30IC - D	Reel of 2500	LMV344IDR	LIVI V 3441
	Quad	TSSOP – PW	Tube of 90	LMV344IPW	MV344I
		1330F - FW	Reel of 2000	LMV344IPWR	IVI V 3441

- (1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
- (2) DBV/DCK/DGK: The actual top-side marking has one additional character that designates the assembly/test site.

APPLICATION CIRCUIT: SAMPLE-AND-HOLD CIRCUIT





SLOS447G-SEPTEMBER 2004-REVISED FEBRUARY 2006

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V ₊	Supply voltage ⁽²⁾				5.5	V
V_{ID}	Differential input voltage (3)			±5.5	V	
V_{I}	Input voltage range (either input)		0	5.5	V	
		Dinaskana	8 pin		97	
	Declare the week introduces (4)(5)	D package	14 pin		86	
0		DBV package		165	°C/W	
θ_{JA}	Package thermal impedance ⁽⁴⁾⁽⁵⁾	DCK package		259		
		DGK package	DGK package			172
		PW package		113		
T_J	Operating virtual junction temperature		150	°C		
T _{stg}	Storage temperature range	-65	150	°C		

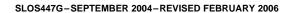
- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values (except differential voltages and V₊ specified for the measurement of I_{OS}) are with respect to the network GND.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_J(max) T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (5) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

		MIN	MAX	UNIT
V ₊	Supply voltage (single-supply operation)	2.5	5.5	V
T _A	Operating free-air temperature	-40	125	°C

ESD Protection

TEST CONDITIONS	TYP	UNIT
Human-Body Model	2000	V
Machine Model	200	V





Electrical Characteristics

 $\rm V_{+}$ = 2.7 V, GND = 0 V, $\rm V_{IC}$ = $\rm V_{O}$ = $\rm V_{+}/2,~R_{L}$ > 1 $\rm M\Omega$ (unless otherwise noted)

	PARAMETER	TEST CONDIT	IONS	T _A	MIN	TYP ⁽¹⁾	MAX	UNIT
V	Input offeet voltage			25°C		0.25	4	mV
V _{IO}	Input offset voltage			Full range			4.5	IIIV
α_{VIO}	Average temperature coefficient of input offset voltage			Full range		1.7		μV/°C
				25°C		1	120	- Λ
I_{IB}	Input bias current			-40°C to 85°C			250	pА
				–40°C to 125°C			3	nA
I _{IO}	Input offset current			25°C		6.6		fA
CMRR	Common mode rejection ratio	$0 \le V_{ICR} \le 1.7 \text{ V}$		25°C	56	80		dB
CIVIKK	Common-mode rejection ratio	$0 \le V_{ICR} \le 1.6 \text{ V}$		Full range	50			uБ
k	Supply-voltage rejection ratio	2.7 V ≤ V ₊ ≤ 5 V		25°C	65	82		dB
k _{SVR}	Supply-voltage rejection ratio	$2.7 V \leq V_{+} \leq 3 V$		Full range	60			uБ
V _{ICR}	Common-mode input voltage range	CMRR ≥ 50 dB		25°C	0	-0.2 to 1.9	1.7	V
		P = 10 kO to 1 25 V		25°C	78	113		
^	Lorge signal valtage gain (2)	$R_L = 10 \text{ k}\Omega \text{ to } 1.35 \text{ V}$		Full range	70			٩D
A_V	Large-signal voltage gain (2)	D 2 k0 to 1 25 V		25°C	72	103		dB
		$R_L = 2 k\Omega$ to 1.35 V		Full range	64			
			Laurlaural	25°C		24	60	
		D 01:0 to 4.05 V	Low level	Full range			95	
		$R_L = 2 k\Omega$ to 1.35 V	High Inval	25°C		26	60	mV
V	Output swing (delta from supply rails)		High level	Full range	·		95	
V _O		D 40101: 405 V	Low level	25°C	·	5	30	
				Full range			40	
		$R_L = 10 \text{ k}\Omega \text{ to } 1.35 \text{ V}$	High level	25°C	·	5.3	30	
				Full range	·		40	
	Supply ourrent (per channel)			25°C		100	170	^
I _{CC}	Supply current (per channel)			Full range			230	μΑ
1	Output short-circuit current	Sourcing	LMV341, LMV342	25°C	20	32		mA
I _{OS}	Output short-circuit current		LMV344	25 0	18	24		ША
		Sinking			15	24		
SR	Slew rate	$R_L = 10 \text{ k}\Omega^{(3)}$		25°C		1		V/μs
GBM	Unity-gain bandwidth	$R_L = 10 \text{ k}\Omega, C_L = 200$	pF	25°C 25°C		1		MHz
Φ_{m}	Phase margin	$R_L = 100 \text{ k}\Omega$	$R_L = 100 \text{ k}\Omega$			72		deg
G _m	Gain margin	$R_L = 100 \text{ k}\Omega$		25°C		20		dB
V _n	Equivalent input noise voltage	f = 1 kHz		25°C		40		nV/√ Hz
In	Equivalent input noise current	f = 1 kHz		25°C		0.001		pA/√ Hz
THD	Total harmonic distortion	$f = 1 \text{ kHz}, A_V = 1, \\ R_L = 600 \Omega, V_I = 1 V_{PI}$	5	25°C		0.017		%

 ⁽¹⁾ Typical values represent the most likely parametric norm.
 (2) GND + 0.2 V ≤ V_O ≤ V₊ − 0.2 V
 (3) Connected as voltage follower with 2-V_{PP} step input. Number specified is the slower of the positive and negative slew rates.

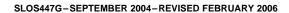


SLOS447G-SEPTEMBER 2004-REVISED FEBRUARY 2006

Shutdown Characteristics

 $\rm V_{+} = 2.7~V,~GND = 0~V,~V_{IC} = V_{O} = V_{+}/2,~R_{L} > 1~M\Omega$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	T _A	MIN TYP	MAX	TINU	
I _{CC(SHDN)}	Cumply augrent in abutdayan mada	V 0.V	25°C	0.045	1000	nΑ	
	Supply current in shutdown mode	$V_{SD} = 0 V$	Full range		1.5	μΑ	
t _(on)	Amplifier turn-on time		25°C	5		μs	
V	Shutdown nin voltage range	ON mode	25°C	1.7 to 2.7	2.4 to 2.7	V	
V_{SD}	Shutdown pin voltage range	Shutdown mode	25 C	0 to 1	0 to 0.8	V	





Electrical Characteristics

 $\rm V_{+} = 5~V,~GND = 0~V,~V_{IC} = V_{O} = V_{+}/2,~R_{L} > 1~M\Omega$ (unless otherwise noted)

	PARAMETER	TEST CONDIT	TIONS	T _A	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IO}	Input offset voltage			25°C		0.25	4	mV
VЮ	input onset voltage			Full range			4.5	IIIV
α_{VIO}	Average temperature coefficient of input offset voltage			Full range		1.9		μV/°C
				25°C		1	200	pA
I_{IB}	Input bias current			–40°C to 85°C			375	pΑ
				–40°C to 125°C			5	nA
I _{IO}	Input offset current			25°C		6.6		fA
CMRR	Common-mode rejection ratio	$0 \le V_{ICR} \le 4 V$		25°C	56	86		dB
CIVILLE	Common-mode rejection ratio	$0 \le V_{ICR} \le 3.9 \text{ V}$		Full range	50			G
k	Supply voltage rejection ratio	2.7 V ≤ V ₊ ≤ 5 V		25°C	65	82		dB
k _{SVR}	Supply-voltage rejection ratio	$2.7 V \leq V_{+} \leq 3 V$		Full range	60			uБ
V _{ICR}	Common-mode input voltage range	CMRR \geq 50 dB $R_L = 10 \text{ k}\Omega \text{ to } 2.5 \text{ V}$		25°C	0	-0.2 to 4.2	4	V
		B = 10 kO to 2 5 V		25°C	78	116		
^	Lorge signal valtage gain (2)	$R_L = 10 \text{ K}22 \text{ to } 2.5 \text{ V}$		Full range	70			٩D
A_V	Large-signal voltage gain (2)	D 240 to 25 V		25°C	72	107		dB
		$R_L = 2 k\Omega$ to 2.5 V		Full range	64			
			I avv lavval	25°C		32	60	
		D 01:0 to 0.5 V	Low level	Full range			95	
		$R_L = 2 k\Omega$ to 2.5 V	Lliah laval	25°C	·	34	60	mV
V	Output swing (delta from supply rails)		High level	Full range	·		95	
V _O		D 40104-05V	Low level	25°C		7	30	
				Full range	·		40	
		$R_L = 10 \text{ k}\Omega \text{ to } 2.5 \text{ V}$	I liab lavial	25°C	·	7	30	
			High level	Full range	·		40	
	Supply ourrent (per channel)			25°C		107	200	^
I _{CC}	Supply current (per channel)			Full range			260	μΑ
I _{os}	Output short-circuit current	Sourcing	LMV341, LMV342	25°C	85	113		mA
ios	Output short circuit current		LMV344	25 0	TBD	TBD		ША
		Sinking			50	75		
SR	Slew rate	$R_L = 10 \text{ k}\Omega^{(3)}$		25°C		1		V/μs
GBM	Unity-gain bandwidth	$R_L = 10 \text{ k}\Omega, C_L = 200$	pF	25°C		1		MHz
Φ_{m}	Phase margin	$R_L = 100 \text{ k}\Omega$		25°C		70		deg
G _m	Gain margin	$R_L = 100 \text{ k}\Omega$		25°C		20		dB
V _n	Equivalent input noise voltage	f = 1 kHz		25°C		39		nV/√ Hz
In	Equivalent input noise current	f = 1 kHz		25°C		0.001		pA/√ Hz
THD	Total harmonic distortion	$f = 1 \text{ kHz}, A_V = 1, \\ R_L = 600 \Omega, V_I = 1 V_P$	P	25°C		0.012		%

 ⁽¹⁾ Typical values represent the most likely parametric norm.
 (2) GND + 0.2 V ≤ V_O ≤ V₊ − 0.2 V
 (3) Connected as voltage follower with 2-V_{PP} step input. Number specified is the slower of the positive and negative slew rates.



SLOS447G-SEPTEMBER 2004-REVISED FEBRUARY 2006

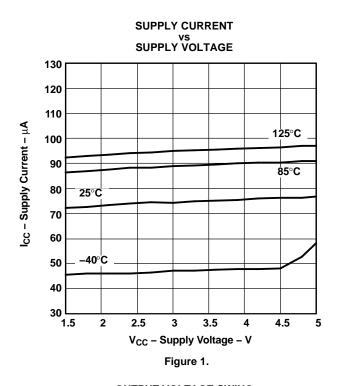
Shutdown Characteristics

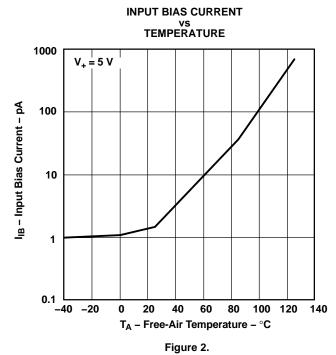
 $\rm V_{+} = 5~V,~GND = 0~V,~V_{IC} = V_{O} = V_{+}/2,~R_{L} > 1~M\Omega$ (unless otherwise noted)

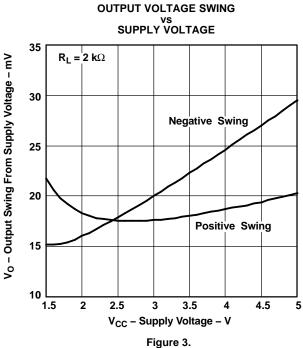
	PARAMETER	TEST CONDITIONS	T _A	MIN TYP	MAX	UNIT	
I _{CC(SHDN)}	Cumply augrent in abutdayan mada	V 0.V	25°C	0.033	1		
	Supply current in shutdown mode	$V_{SD} = 0 V$	Full range		1.5	μΑ	
t _(on)	Amplifier turn-on time		25°C	5		μs	
M	Shutdown nin voltage range	ON mode	25°C	3.1 to 5	4.5 to 5	V	
V_{SD}	Shutdown pin voltage range	Shutdown mode	25 C	0 to 1	0 to 0.8		

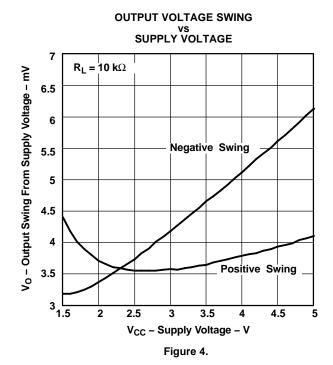


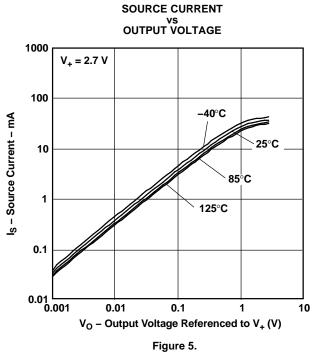
TYPICAL CHARACTERISTICS

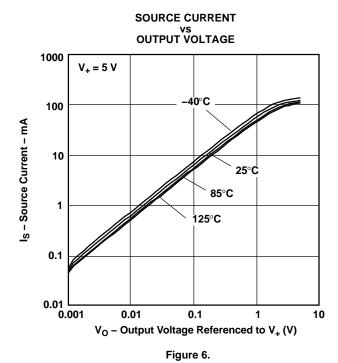


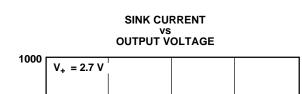


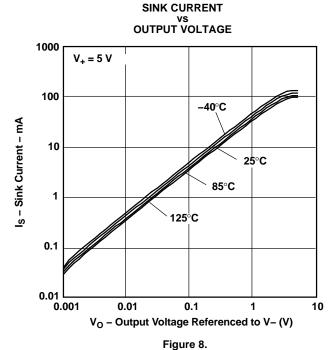












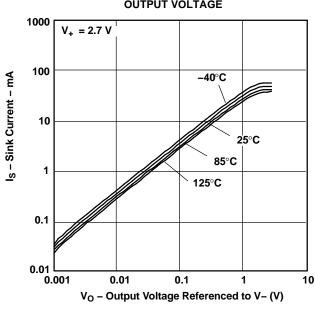
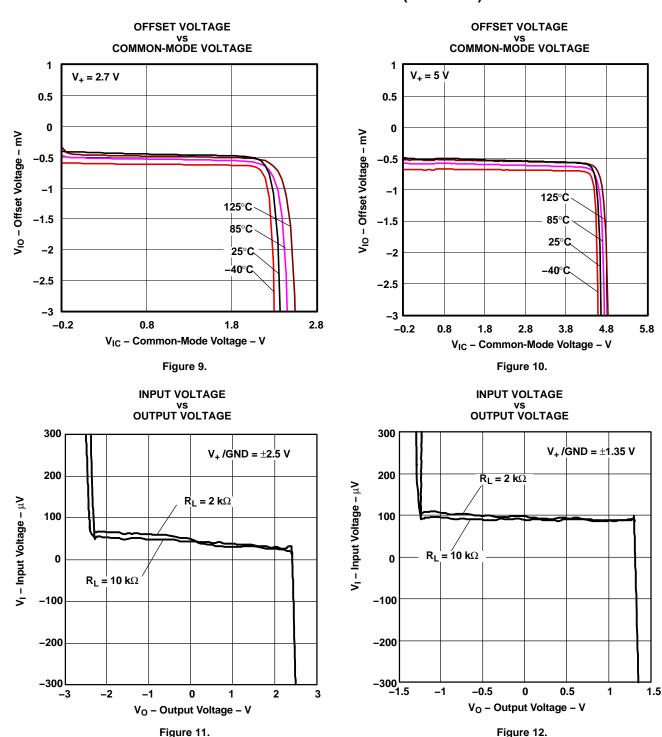
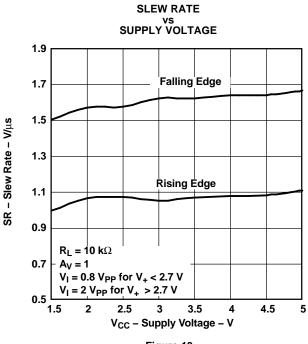


Figure 7.









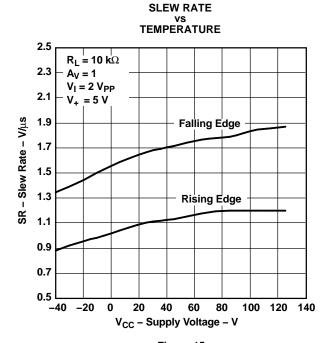


Figure 15.

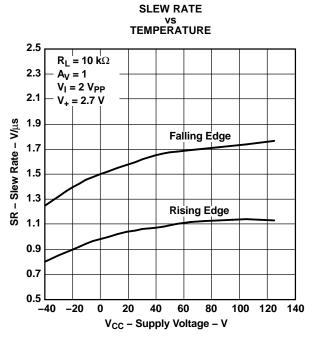


Figure 14.

CMRR

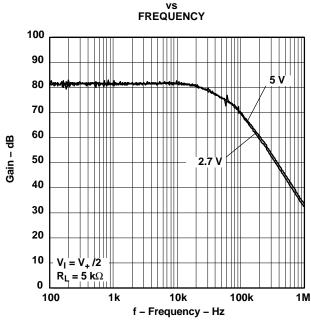


Figure 16.



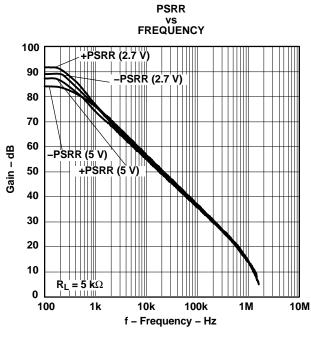


Figure 17.

TOTAL HARMONIC DISTORTION + NOISE vs FREQUENCY

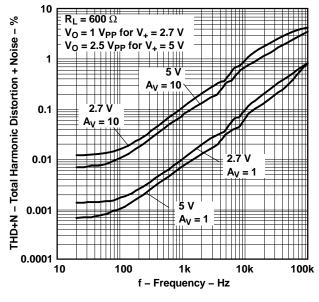
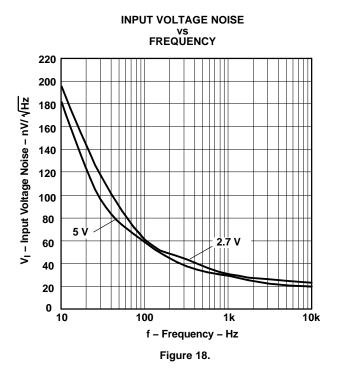
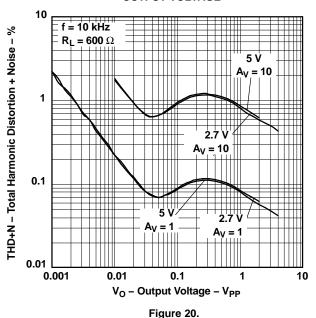


Figure 19.



TOTAL HARMONIC DISTORTION + NOISE vs OUTPUT VOLTAGE





RAIL-TO-RAIL OUTPUT CMOS OPERATIONAL AMPLIFIERS

SLOS447G-SEPTEMBER 2004-REVISED FEBRUARY 2006

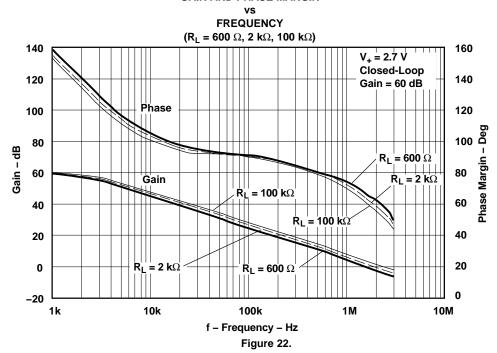
TYPICAL CHARACTERISTICS (continued)

GAIN AND PHASE MARGIN

vs **FREQUENCY** $(T_A = -40^{\circ}C, 25^{\circ}C, 125^{\circ}C)$ 160 140 V₊ = 5 V Phase $R_L = 2 k\Omega$ 140 120 120 100 Phase Margin – Deg 100 80 -40°C Gain - dB Gain 80 60 25°C 60 40 125°C 40 20 25° 125°C 20 0 -20 L 0 10k 100k 1M 10M

f - Frequency - Hz Figure 21.

GAIN AND PHASE MARGIN





GAIN AND PHASE MARGIN

vs **FREQUENCY** $(R_L = 600 \Omega, 2 k\Omega, 100 k\Omega)$ 160 140 V₊ = 5 V Closed-Loop 140 120 Gain = 60 dB Phase 120 100 Phase Margin – Deg 100 80 $R_L = 600 \Omega$ | | | | | | | $R_L = 2 k\Omega$ 80 60 Gain $R_L = 100 \text{ k}\Omega$ 60 40 $R_L = 100 \text{ k}\Omega$ 40 20 $R_L = 2 k\Omega$ $R_L = 600 \Omega$ 20 0 0 10k 100k 1M 10M f - Frequency - Hz

GAIN AND PHASE MARGIN

Figure 23.

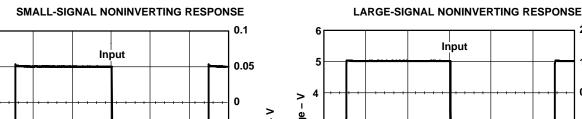
vs **FREQUENCY** $(C_1 = 0 pF, 100 pF, 500 pF, 1000 pF)$ 140 100 Phase V₊ = 5 V $R_L = 600 \Omega$ 120 80 $C_L = 0 pF$ Closed-Loop Gain = 60 dB 100 60 C_L = 100 pF 40 80 C_L = 500 pF Gain C_L = 1000 pF 20 60 40 $C_L = 0 pF$ -20 20 -40 0 $C_{L} = 500 \text{ pF}$ -60 -20 C_L = 1000 pF $C_{L} = 100 pF$ -40 ∟ 1k -80 10k 1M 10M f - Frequency - Hz

0.25

-0.05

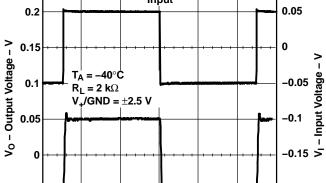
-0.1

TYPICAL CHARACTERISTICS (continued)



-0.2

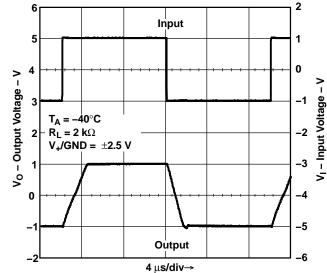
-0.25



Output

4 μs/div→

Figure 25.



SLOS447G-SEPTEMBER 2004-REVISED FEBRUARY 2006

Figure 26.

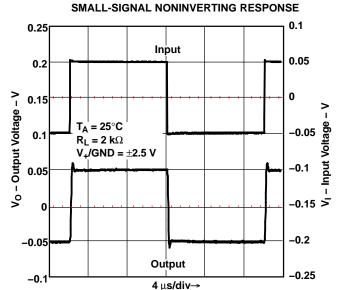


Figure 27.

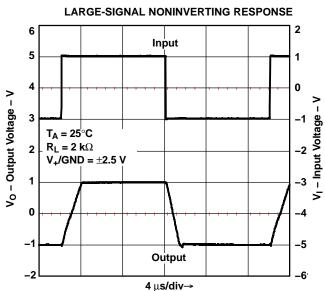
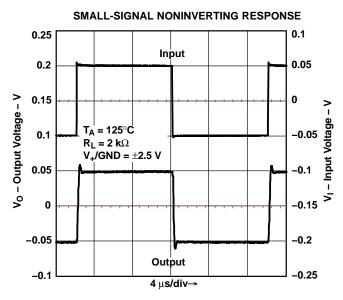


Figure 28.







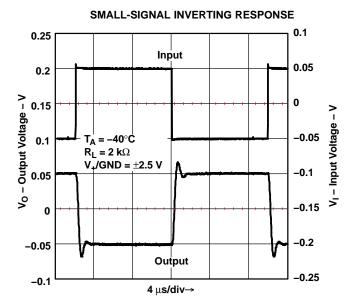


Figure 31.

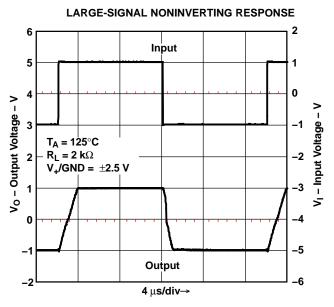


Figure 30.

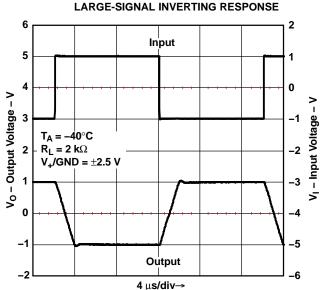


Figure 32.

Figure 36.



TYPICAL CHARACTERISTICS (continued)

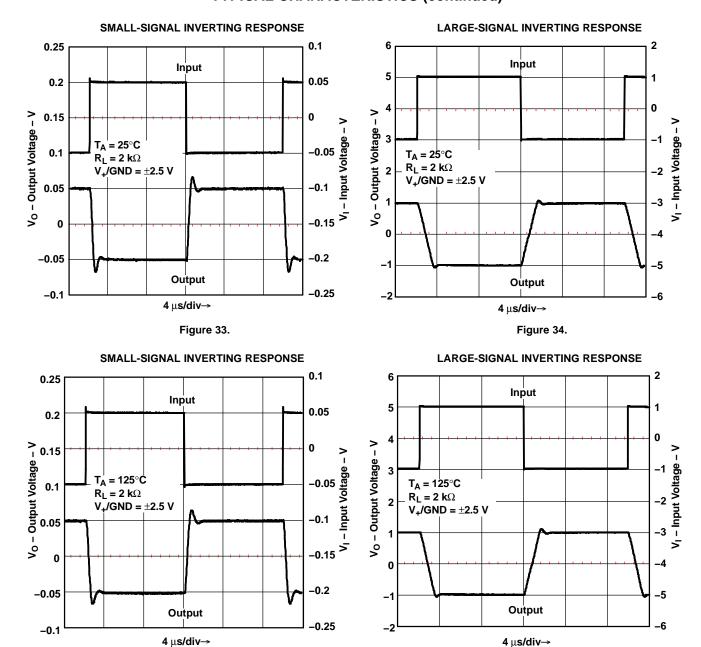


Figure 35.



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
LMV341IDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV341IDBVRE4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV341IDBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV341IDCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV341IDCKRE4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV341IDCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV342ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV342IDDUR	PREVIEW	VSSOP	DDU	8	3000	TBD	Call TI	Call TI
LMV342IDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV342IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV342IDGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV342IDGKRG4	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV342IDGKT	PREVIEW	MSOP	DGK	8	250	TBD	Call TI	Call TI
LMV342IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV342IDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV342IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV344ID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV344IDE4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV344IDG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV344IDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV344IDRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV344IDRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV344IPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV344IPWE4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV344IPWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LMV344IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM



PACKAGE OPTION ADDENDUM

16-Oct-2008

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins Packa Qty	-	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
					no Sb/Br)		
LMV344IPWRE4	ACTIVE	TSSOP	PW	14 200	O Green (RoHS & no Sb/Br)	& CU NIPDAU	Level-1-260C-UNLIM
LMV344IPWRG4	ACTIVE	TSSOP	PW	14 200	O Green (RoHS & no Sb/Br)	& CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF LMV344:

Automotive: LMV344-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects





i.com 5-Dec-2008

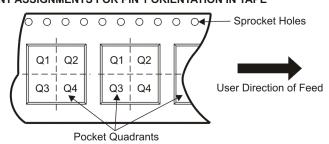
TAPE AND REEL INFORMATION



TAPE DIMENSIONS KO P1 BO W Cavity A0

	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV341IDBVR	SOT-23	DBV	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV341IDCKR	SC70	DCK	6	3000	180.0	8.4	2.24	2.34	1.22	4.0	8.0	Q3
LMV342IDGKR	MSOP	DGK	8	2500	330.0	13.0	5.3	3.4	1.4	8.0	12.0	Q1
LMV342IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LMV344IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV344IPWR	TSSOP	PW	14	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV341IDBVR	SOT-23	DBV	6	3000	195.0	200.0	45.0
LMV341IDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
LMV342IDGKR	MSOP	DGK	8	2500	358.0	335.0	35.0
LMV342IDR	SOIC	D	8	2500	340.5	338.1	20.6
LMV344IDR	SOIC	D	14	2500	346.0	346.0	33.0
LMV344IPWR	TSSOP	PW	14	2000	346.0	346.0	29.0

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

DDU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation CA.



DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

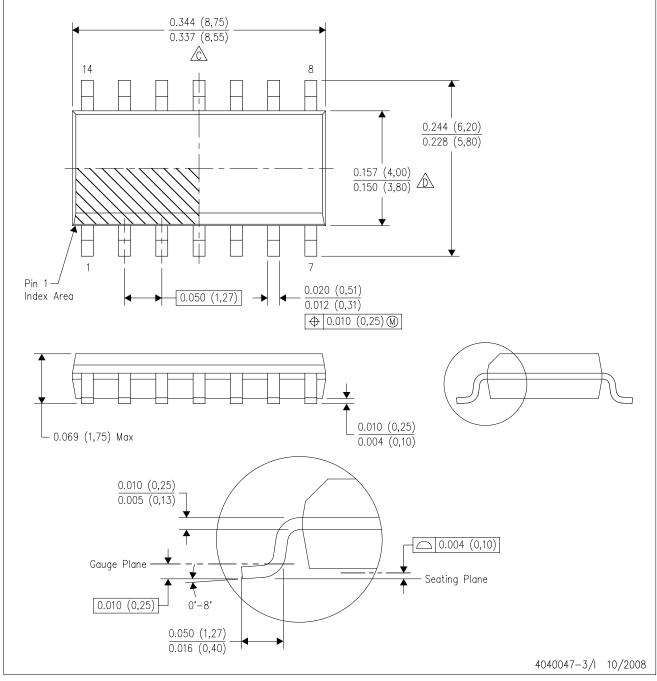


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AB.



DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AB.



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